

### MiniSKiiP<sup>®</sup> 2

### Sixpack

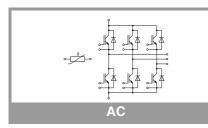
#### SKiiP 23AC12T4V1

#### Features\*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

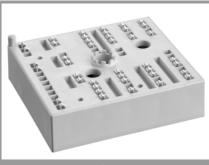
#### Remarks

- Max. case temperature limited to  $T_{C}{=}125^{\circ}C$
- Product reliability results valid for  $T_j \le 150^{\circ}C$  (recommended  $T_{j,op} = -40...+150^{\circ}C$ )
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information



Symbol	Conditions			Values				
Inverter -	IGBT							
V <sub>CES</sub>	T <sub>i</sub> = 25 °C			1200				
lc	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C		41				
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C		34				
I <sub>C</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C		46				
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C		37				
I <sub>Cnom</sub>				25		Α		
I <sub>CRM</sub>	_			75		Α		
V <sub>GES</sub>				-20 20		V		
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 150 °C		10				
Tj		1		-40 175				
Inverse -	Diode							
V <sub>RRM</sub>	T <sub>i</sub> = 25 °C			1200				
l <sub>F</sub>	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C		32				
	$T_j = 175 ^{\circ}C$	T <sub>s</sub> = 70 °C		26				
l <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C		35		А		
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C		28				
I <sub>FRM</sub>				75				
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°	°, T <sub>j</sub> = 150 °C		100				
Tj				-40 175				
Module	·							
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20	A per spring		100				
T <sub>stg</sub>	module without TIM	1		-40 125				
V <sub>isol</sub>	AC sinus 50 Hz, t =	1 min		2500				
Characte	eristics							
Symbol	Conditions		min.	typ.	max.	Unit		
Inverter -	IGBT							

Symbol	Conditions			typ.	max.	Unit	
Inverter -	IGBT						
V <sub>CE(sat)</sub>	$I_{\rm C} = 25  {\rm A}$	T <sub>j</sub> = 25 °C		1.85	2.10	V	
	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 150 °C		2.25	2.45	V	
V <sub>CE0</sub>	chiplevel	T <sub>j</sub> = 25 °C		0.80	0.90	V	
	emplevel	T <sub>j</sub> = 150 °C		0.70	0.80	V	
r <sub>CE</sub>	$V_{GE} = 15 V$	T <sub>j</sub> = 25 °C		42	48	mΩ	
	chiplevel	T <sub>j</sub> = 150 °C		62	66	mΩ	
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_C = 1 \text{ m}$	A	5.3	5.8	6.3	V	
I <sub>CES</sub>	$V_{GE} = 0 V, V_{CE} = 12$	200 V, T <sub>j</sub> = 25 °C			1	mA	
Cies	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	f = 1 MHz		1.45		nF	
Coes		f = 1 MHz		0.12		nF	
C <sub>res</sub>		f = 1 MHz		0.05		nF	
Q <sub>G</sub>	V <sub>GE</sub> = - 8 V+ 15 V	•		142		nC	
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			0		Ω	
t <sub>d(on)</sub>	$V_{CC} = 600 V$	T <sub>j</sub> = 150 °C		44			
t <sub>r</sub>	$I_{\rm C} = 25 \text{ A}$ $R_{\rm G on} = 39 \Omega$	T <sub>j</sub> = 150 °C		46		ns	
Eon	$R_{G off} = 39 \Omega$	T <sub>j</sub> = 150 °C	j = 150 °C 3.7				
t <sub>d(off)</sub>	di/dt <sub>on</sub> = 465 A/µs	T <sub>j</sub> = 150 °C	330			ns	
t <sub>f</sub>	di/dt <sub>off</sub> = 350 A/µs	T <sub>j</sub> = 150 °C	62			ns	
E <sub>off</sub>	V <sub>GE</sub> = +15/-15 V	T <sub>j</sub> = 150 °C			mJ		
R <sub>th(j-s)</sub>	per IGBT, $\lambda_{paste}=0.3$	8 W/(mK)	1	K/W			
R <sub>th(j-s)</sub>	per IGBT, $\lambda_{\text{paste}}=2.5$	5 W/(mK)		0.83		K/W	



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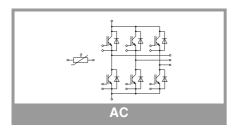
#### Features\*

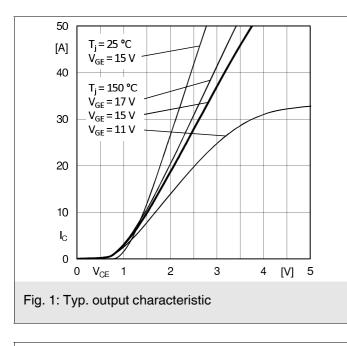
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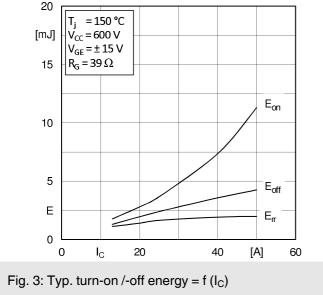
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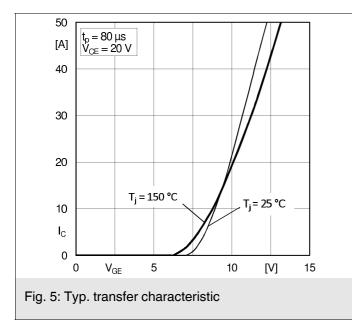
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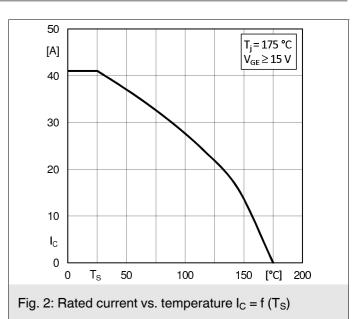
Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I <sub>F</sub> = 25 A	T <sub>j</sub> = 25 °C		2.41	2.74	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 150 °C		2.45	2.79	V
V <sub>F0</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.30	1.50	V
	chiplevel	T <sub>j</sub> = 150 °C		0.90	1.10	V
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		44	50	mΩ
	chiplevel	T <sub>j</sub> = 150 °C		62	68	mΩ
I <sub>RRM</sub>	$I_{\rm F} = 25  {\rm A}$	T <sub>j</sub> = 150 °C		19		А
Q <sub>rr</sub>	di/dt <sub>off</sub> = 640 A/μs V <sub>GF</sub> = +15/-15 V	T <sub>j</sub> = 150 °C		4		μC
E <sub>rr</sub>	$V_{CC} = 600 V$	T <sub>j</sub> = 150 °C	50 °C			mJ
R <sub>th(j-s)</sub>	per Diode, $\lambda_{paste}=0$	.8 W/(mK)		1.52		K/W
R <sub>th(j-s)</sub>	per Diode, $\lambda_{paste}=2$	.5 W/(mK)		1.29		K/W
Module	·					
L <sub>CE</sub>				-		nH
Ms	to heat sink		2		2.5	Nm
w				55		g
Temperat	ure Sensor					
R <sub>100</sub>	T <sub>r</sub> =100°C (R <sub>25</sub> =100		1670 ± 3%		Ω	
R <sub>(T)</sub>	$ \begin{array}{l} R_{(T)} = 1000 \Omega [1 + \mathrm{A} (\mathrm{T} \text{-} 25^{\circ} \mathrm{C}) + \mathrm{B} (\mathrm{T} \text{-} 25^{\circ} \mathrm{C})^2] \\ \text{, } A = 7.635^* 10^{-3 \circ} \mathrm{C}^{-1}, \\ B = 1.731^* 10^{-5 \circ} \mathrm{C}^{-2} \end{array} $					

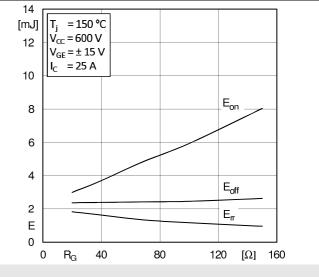


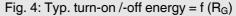


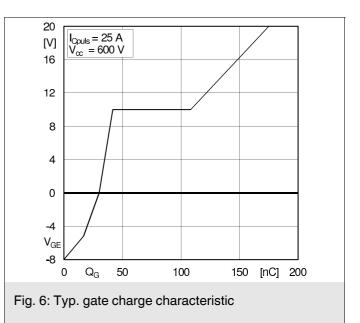


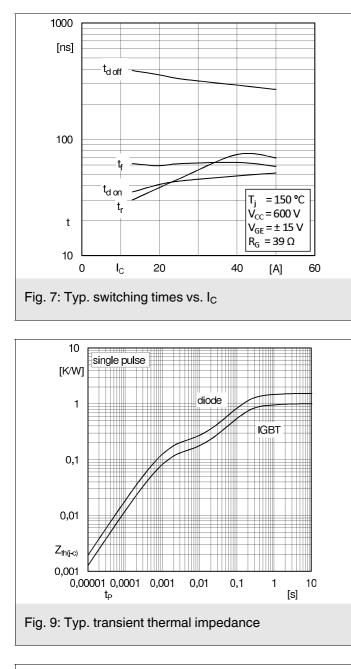


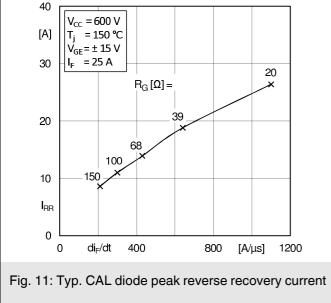


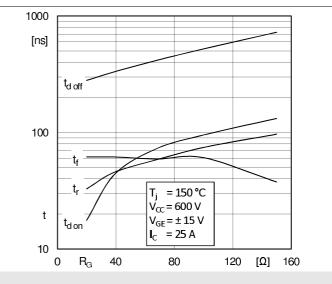


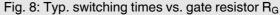


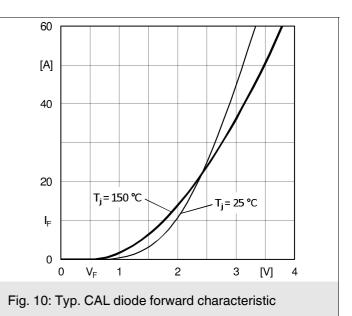


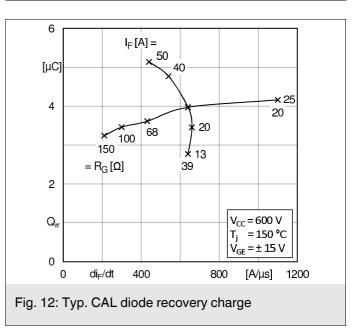






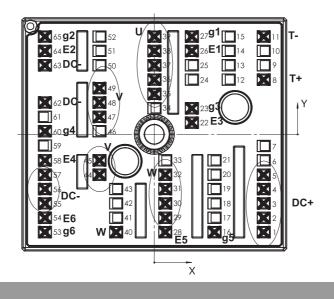




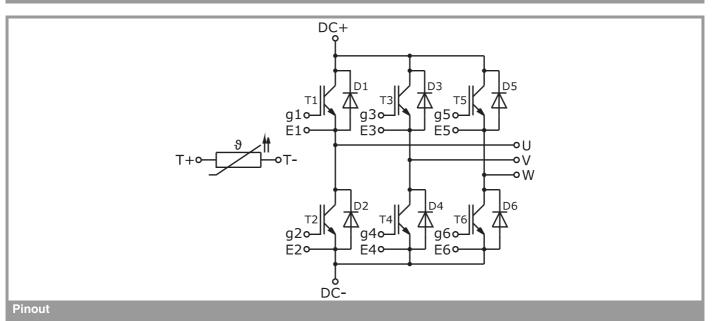


Pin out											
Pin	X	Ŷ	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	24,38	-21,80	DC+	23	8,38	5,80	g3	45	-12,23	-5,80	V
2	24,38	-18,60	DC+	24	8,38	12,20		46	-12,23	0,70	
3	24,38	-15,40	DC+	25	8,38	15,40		47	-12,23	3,90	V
4	24,38			26	8,38		E1	48	-12,23		
5	24,38	-9,00	DC+	27	8,38	21,80	g1	49	-12,23	10,30	V
6	24,38	-5,80		28	2,46	-21,80	E5	50	-12,23	15,40	
7	24,38	-2,60		29	2,46	-18,60	W	51	-12,23	18,60	
8	24,38	12,20	T+	30	2,46	-15,40	W	52	-12,23	21,80	
9	24,38	15,40		31	2,46	-12,20	W	53	-24,38	-21,80	g6
10	24,38	18,60		32	2,46	-9,00	W	54	-24,38	-18,60	E6
11	24,38	21,80	Т-	33	2,46	-5,80		55	-24,38	-15,40	DC-
12	16,58	12,20		34	0,03	5,80		56	-24,38	-12,20	DC-
13	16,58	15,40		35	0,03	9,00	U	57	-24,38	-9,00	DC-
14	16,58	18,60		36	0,03	12,20	U	58	-24,38	-5,80	E4
15	16,58	21,80		37	0,03	15,40	U	59	-24,38	-2,50	
16	13,42	-21,80	g5	38	0,03	18,60	U	60	-24,38	0,70	g4
17	13,42	-18,60		39	0,03	21,80	U	61	-24,38	3,90	
18	13,42	-15,40		40	-8,51	-21,80	W	62	-24,38	7,10	DC-
19	13,42	-12,20		41	-8,51	-18,60		63	-24,38	15,40	DC-
20	13,42			42	-8,51			64	-24,38		E2
21	13,42	-5,80		43	-8,51	-12,20		65	-24,38	21,80	g2
22	8,38	2,60	E3	44	-12,23	-9,00	V				

all values in mm



**Pinout and Dimensions** 



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

#### **\*IMPORTANT INFORMATION AND WARNINGS**

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